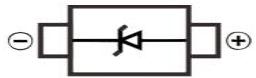


SOD-523 Schottky Barrier Diode 肖特基势垒二极管**■ Internal Configuration& Device Marking 内部结构与产品打标**

Type 型号	RB520S-40		
Pin 管脚	 		
Mark 打标			

■ Absolute Maximum Ratings 最大额定值

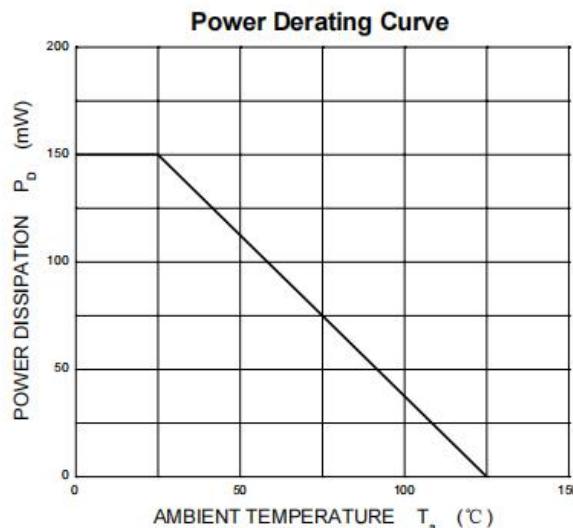
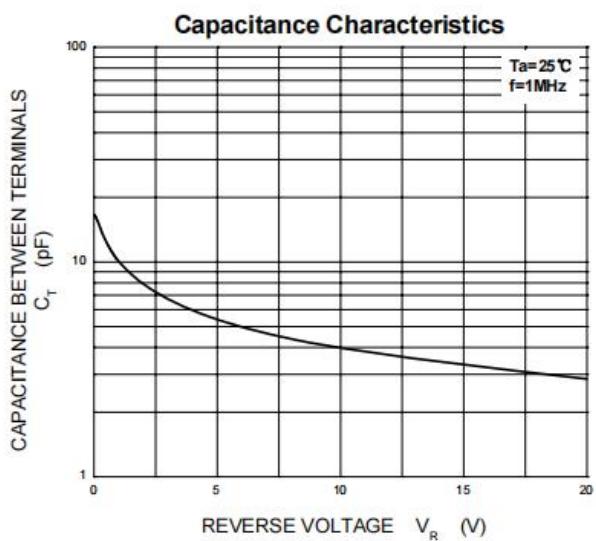
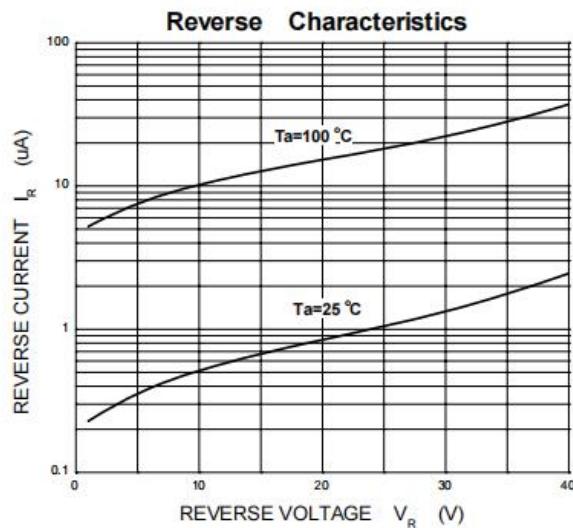
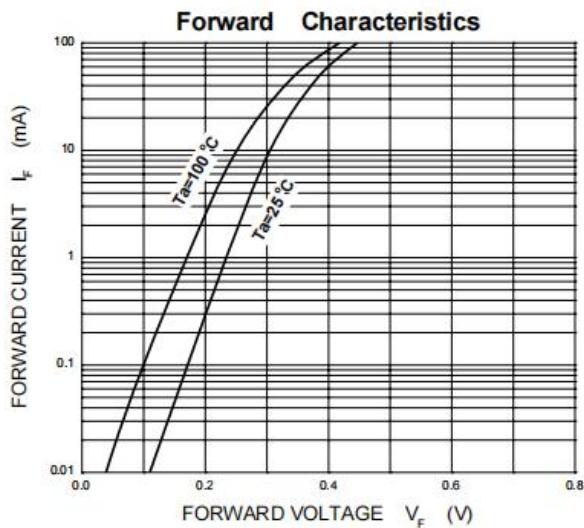
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
DC Reverse Voltage 直流反向电压	V _R	40	V
Forward Work Current 正向工作电流	I _O	200	mA
Peak Forward Surge Current 正向峰值浪涌电流	I _{FSM}	1000	mA
Power dissipation 耗散功率	P _D (Ta=25°C)	150	mW
Thermal Resistance J-A 结到环境热阻	R _{θJA}	668	°C/W
Junction and Storage Temperature 结温和储藏温度	T _J , T _{stg}	-55to+125°C	

■ Electrical Characteristics 电特性

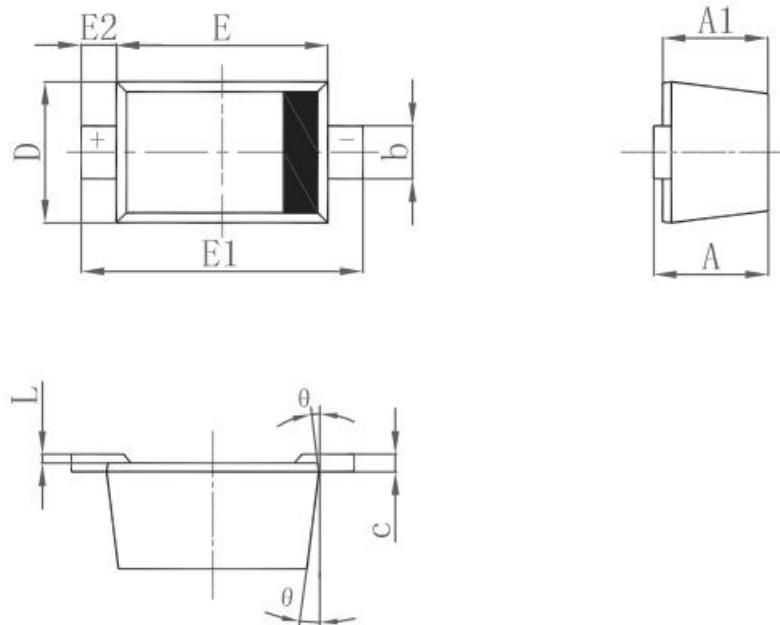
(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Max 最大值	Unit 单位
Reverse Breakdown Voltage 反向击穿电压(IR=100μA)	V _(BR)	40	—	V
Reverse Leakage Current(VR=10V) 反向漏电流(VR=40V)	I _R	—	1 10	μA
Forward Voltage(IF=10mA) 正向电压(IF=100mA)	V _F	—	0.39 0.55	V

■Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.510	0.770	0.020	0.031
A1	0.500	0.700	0.020	0.028
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	0.750	0.850	0.030	0.033
E	1.100	1.300	0.043	0.051
E1	1.500	1.700	0.059	0.067
E2	0.200 REF		0.008 REF	
L	0.010	0.070	0.001	0.003
θ	7° REF		7° REF	